

Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



EPITAXIAL SILICON POWER TRANSISTORS

PIN CONFIGURATION
1. BASE
2. COLLECTOR
3. EMITTER

CJD175 | CJD176 CJD177 | CJD178 CJD179 | CJD180 NPN | PNP

PNP 0-252)

DPAK (TO-252) Plastic Package

Intended for use in Medium Power Linear Switching Applications

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	CJD175 CJD176	CJD177 CJD178	CJD179 CJD180	UNIT
Collector -Emitter Voltage	V_{CEO}	45	60	80	V
Collector -Base Voltage	V_{CBO}	45	60	80	V
Emitter Base Voltage	V_{EBO}	5.0			
Collector Current	I _C	3.0			
Collector Peak Current	I _{CM}	7.0			
Power Dissipation @ T _a =25°C	P_{D}	1.25			
Derate above 25°C		10			mW/ºC
Power Dissipation @ T _c =25°C	P_{D}	30			W
Operating and Storage Junction Temperature Range	T _j , T _{stg}	- 65 to +150			°C

THERMAL CHARACTERISTICS

Junction to Ambient in free air	R _{th (j-a)}	100	°C/W
Junction to Case	R _{th (j-c)}	4.16	°C/W

ELECTRICAL CHARACTERISTICS (T_c=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION		MIN	MAX	UNIT
Collector Cut off Current	I _{CBO}	$V_{CB}=45V_{,}I_{E}=0$	CJD175/76		100	μΑ
		$V_{CB}=60V$, $I_{E}=0$	CJD177/78		100	μA
		$V_{CB}=80V, I_{E}=0$	CJD179/80		100	μΑ
Emitter Cut off Current	I _{EBO}	$V_{EB}=5V$, $I_{C}=0$			1.0	mA
Collector Emitter Sustaining Voltage	*V _{CEO (sus)}	$I_C=100$ mA, $I_B=0$	CJD175/76	45		V
			CJD177/78	60		V
			CJD179/80	80		V
Collector Emitter Saturation Voltage	*V _{CE (sat)}	$I_{C}=1A, I_{B}=0.1A$			0.8	V
Base Emitter on Voltage	*V _{BE (on)}	$I_C=1A, V_{CE}=2V$			1.3	V
DC Current Gain	*h _{FE}	$I_C=150$ mA, $V_{CE}=2$ V		40		
		$I_C=1A$, $V_{CE}=2V$		15		
	*h _{FE} Group	I _C =150mA, V _{CE} =2V	- 6	40	100	
		· ·	- 10	63	160	
		Only CJD175/76/79	- 16	100	250	
Transition Frequency	f _T	I _C =250mA, V _{CE} =10V		3.0		MHz

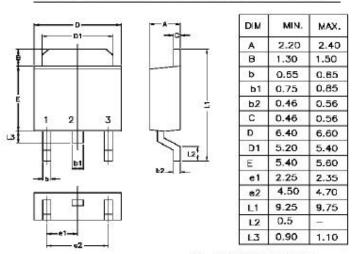
^{*}Pulse test:- Pulse width=300ms, Duty cycle=1.5%

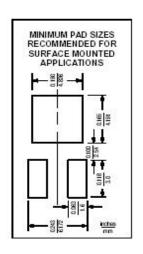
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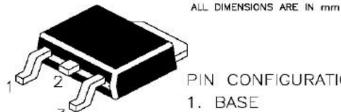
CJD176 CJD175 CJD178 CJD177 CJD180 CJD179 PNP NPN

DPAK (TO-252) Plastic Package

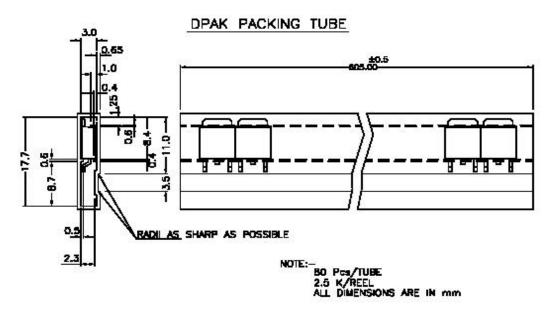
DPAK PACKAGE OUTLINE DIMENSIONS







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Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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